ISL97645A

Boost + VON Slice + VCOM + Reset

The ISL97645A represents an integrated DC/DC regulator for monitor and notebook applications with screen sizes up to 20". The device integrates a boost converter for generating A_{VDD}, a V_{ON} slice circuit, and a high performance V_{COM} amplifier.

The boost converter features a 2.6A FET and has user programmable soft-start and compensation. With efficiencies up to 92%, the A_{VDD} is user selectable from 7V to 20V.

The V_{ON} slice circuit can control gate voltages up to 30V. High and low levels are programmable, as well as discharge rate and timing.

The supply monitor can be used to monitor the input voltage to prevent low voltage operation.

The integrated V_{COM} features high speed and drive capability. With 30MHz bandwidth and 50V/µs slew rate, the V_{COM} amplifier is capable of driving 400mA peaks, and 100mA continuous output current.

Ordering Information

PART NUMBER (Notes 1, 2, 3)	PART MARKING	TEMP. RANGE (°C)	PACKAGE (Pb-Free)	PKG. DWG. #
ISL97645AIRZ	976 45AIRZ	-40 to +85	24 Ld 4x4 QFN	L24.4x4D

NOTES:

1. Add "-T*" suffix for tape and reel. Please refer to TB347 for details on reel specifications.

2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

3. For Moisture Sensitivity Level (MSL), please see device information page for ISL97645A. For more information on MSL please see techbrief TB363.
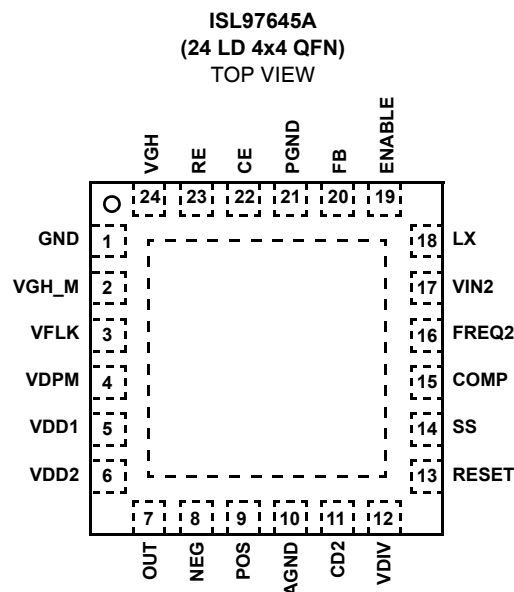
Features

- 2.7V to 5.5V Input
- 2.6A Integrated Boost for Up to 20V A_{VDD}
- Integrated V_{ON} Slice
- RESET signal generated by Supply Monitor
- 600kHz/1.2MHz f_S
- V_{COM} Amplifier
  - 30MHz BW
  - 50V/µs SR
  - 400mA Peak Output Current
- UV and OT Protection
- 24 Ld 4x4 QFN
- Pb-Free (RoHS Compliant)

Applications

- LCD Monitors (15"+)
- Notebook Display (up to 16")

Pinout

ISL97645A
(24 LD 4x4 QFN)
TOP VIEW

Pin Descriptions

PIN NUMBER	NAME	DESCRIPTION
1	GND	Signal ground
2	VGH_M	Gate Pulse Modulator Output
3	VFLK	Gate Pulse Modulator Control input
4	VDPM	Gate Pulse Modulator Enable. Connect a capacitor from VDPM to GND to set the delay time before GPM is enabled. A 20µA current source charges CDPM. Power on delay time = 60.75k*CDPM.
5	VDD1	Gate Pulse Modulator Low Voltage Input
6	VDD2	VCOM Amplifier Supply
7	OUT	VCOM Amplifier Output
8	NEG	VCOM Amplifier Inverting input
9	POS	VCOM Amplifier Non-inverting input
10	AGND	VCOM Amplifier Ground
11	CD2	Voltage detector rising edge delay. Connect a capacitor between this pin and GND to set the rising edge delay.
12	VDIV	Voltage detector threshold. Connect to the center of a resistive divider between V_{IN} and GND.
13	RESET	Voltage detector reset output.
14	SS	Boost Converter Soft-Start. Connect a capacitor between this pin and GND to set the soft-start time.
15	COMP	Boost Converter Compensation pin. Connect a series resistor and capacitor between this pin and GND to optimize transient response.
16	FREQ	Boost Converter frequency select
17	VIN2	Boost Converter power supply
18	LX	Boost Converter Switching Node
19	ENABLE	Chip Enable pin. Connect to VIN1 for normal operation, GND for shutdown.
20	FB	Boost Converter Feedback
21	PGND	Boost Converter Power Ground
22	RE	Gate Pulse Modulator Slew Control. Connect a resistor between this pin and GND to set the falling slew rate.
23	CE	Gate Pulse Modulator Delay Control. Connect a capacitor between this pin and GND to set the delay time.
24	VGH	Gate Pulse Modulator High Voltage Input

Absolute Maximum Ratings

Lx to GND, AGND and PGND . . . .-0.5 to +25V
VDD2, OUT, NEG and POS
  to GND, AGND and PGND. . . . .-0.5 to +25V
VDD1, VGH and VGH_M
  to GND, AGND and PGND. . . . .-0.5 to +32V
Differential Voltage Between POS and NEG . . . . ±6V
Voltage Between GND, AGND and PGND . . . . ±0.5V
All Other Pins to GND, AGND and PGND . . . . -0.5 to +6.5V
Input, Output, or I/O Voltage . . . . .GND -0.3V to VIN + 0.3V

Recommended Operating Conditions

Input Voltage Range, VS . . . . .2.7V to 5.5V
Boost Output Voltage Range, AV_{DD}. . . . . 8V to 20V
Input Capacitance, C_{IN}. 22µF
Boost Inductor, L1 . . . . 3.3µH to 10µH
Output Capacitance, C_{OUT}. . . . . .2µF x 22µF
Operating Ambient Temperature Range . . . .-40°C to +85°C
Operating Junction Temperature . . . .-40°C to +125°C

Thermal Information

Thermal Resistance	θ_{JA} (°C/W)	θ_{JC} (°C/W)

4x4 QFN Package (Notes 4, 5)   39   2.5
Storage Temperature . . . .-65°C to +150°C
Maximum Continuous Junction Temperature . . . . +125°C
Power Dissipation
  $T_A \le$ +25°C 2.44W
  T_A = +70°C 1.34W
  T_A = +85°C 0.98W
  T_A = +100°C 0.61W
Pb-Free Reflow Profile   see link below
  http://www.intersil.com/pbfree/Pb-FreeReflow.asp

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

4. θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.

5. For θ_{JC}, the "case temp" location is the center of the exposed metal pad on the package underside.

Electrical Specifications

V_{IN} = ENABLE = 5V, V_{DD1} = V_{DD2} = 14V, V_{GH} = 25V, AV_{DD} = 10V, T_A = -40°C to +85°C Unless Otherwise Noted. **Boldface limits apply over the operating temperature range, -40°C to +85°C.**

SYMBOL	PARAMETER	TEST CONDITION	MIN (Note 6)	TYP	MAX (Note 6)	UNIT
GENERAL						
V_S	V_{IN} Input Voltage Range		**2.7**	3.3	**5.5**	V
I_{S_DIS}	V_{IN} Supply Currents when Disabled	ENABLE = 0V		1	**3.5**	µA
I_S	V_{IN} Supply Currents	ENABLE = 5V, LX not switching		1		mA
UVLO	Under Voltage Lockout Threshold	V_{IN2} Rising	**2.3**	2.45	**2.6**	V
		V_{IN2} Falling	**2.2**	2.35	**2.5**	V
OT_R	Thermal Shutdown Temperature	Temperature Rising		140		°C
OT_F		Temperature Falling		100		°C
LOGIC INPUT CHARACTERISTICS - ENABLE, VFLK, FREQ, VDPM						
V_{IL}	Low Voltage Threshold				**0.8**	V
V_{IH}	High Voltage Threshold		**2.2**			V
R_{IL}	Pull-Down Resistor	Enabled, Input at V_{IN}	**150**	250	**400**	kΩ
STEP-UP SWITCHING REGULATOR						
A_{VDD}	Output Voltage Range		V_{IN}*1.25		**20**	V
ΔVBOOST/ΔIOUT	Load Regulation	50mA < I_{LOAD} < 250mA		0.2		%
ΔVBOOST/ΔVIN	Line Regulation	I_{LOAD} = 150mA, 3.0 < V_{IN} < 5.5V		0.15	**0.25**	%
ACC_{AVDD}	Overall Accuracy (Line, Load, Temperature)	10mA < I_{LOAD} < 300mA, 3.0 < V_{IN} < 5.5V, 0°C < T_A < +85°C	**-3**		**3**	%
V_{FB}	Feedback Voltage (V_{FB})	I_{LOAD} = 100mA, T_A = +25°C	1.20	1.21	1.22	V
		I_{LOAD} = 100mA, T_A = -40°C to +85°C	**1.19**	1.21	**1.23**	V

Electrical Specifications V_{IN} = ENABLE = 5V, V_{DD1} = V_{DD2} = 14V, V_{GH} = 25V, AV_{DD} = 10V, T_A = -40°C to +85°C
Unless Otherwise Noted. **Boldface limits apply over the operating temperature range, -40°C to +85°C. (Continued)**

SYMBOL	PARAMETER	TEST CONDITION	MIN (Note 6)	TYP	MAX (Note 6)	UNIT
I_{FB}	FB Input Bias Current			250	**500**	nA
$r_{DS(ON)}$	Switch ON-resistance			150	**300**	mΩ
EFF	Peak Efficiency			92		%
I_{LIM}	Switch Current Limit			2.9		A
D_{MAX}	Max Duty Cycle		**85**	90		%
f_{OSC}	Oscillator Frequency	FREQ = 0V	**550**	650	**800**	kHz
		FREQ = V_{IN2}	**1.0**	1.2	**1.4**	MHz
I_{SS}	Soft-Start Slew Current	SS < 1V, T_A = +25°C		2.75		µA
V_{COM} AMPLIFIER R_{LOAD} = 10k, C_{LOAD} = 10pF, Unless Otherwise Stated						
V_{SAMP}	Supply Voltage		**4.5**		**20**	V
I_{SAMP}	Supply Current			3		mA
V_{OS}	Offset Voltage			3	**20**	mV
I_B	Noninverting Input Bias Current			0	**100**	nA
CMIR	Common Mode Input Voltage Range		**0**		**VDD2**	V
CMRR	Common-Mode Rejection Ratio		**50**	70		dB
PSRR	Power Supply Rejection Ratio		**70**	85		dB
V_{OH}	Output Voltage Swing High	I_{OUT}(source) = 5mA		VDD2 - 50		mV
V_{OH}	Output Voltage Swing High	I_{OUT}(source) = 50mA		VDD2 - 450		mV
V_{OL}	Output Voltage Swing Low	I_{OUT}(sink) = 5mA		50		mV
V_{OL}	Output Voltage Swing Low	I_{OUT}(sink) = 50mA		450		mV
I_{SC}	Output Short Circuit Current		**250**	400		mA
SR	Slew Rate			50		V/µs
BW	Gain Bandwidth	-3dB gain point		30		MHz
GATE PULSE MODULATOR						
V_{GH}	VGH Voltage		**7**		**30**	V
V_{IH_VDPM}	VDPM Enable Threshold		**1.18**	1.215	**1.25**	V
I_{VGH}	VGH Input Current	VFLK = 0		260		µA
		RE = 33kΩ, VFLK = VDD1		40		µA
V_{DD1}	VDD1 Voltage		**3**		**VGH - 2**	V
I_{VDD1}	VDD1 Input Current		**-2**	0.1	**2**	µA
R_{ONVGH}	VGH to VGH_M On Resistance			70		Ω
I_{DIS_VGH}	VGH_M Discharge Current	RE = 33kΩ		8		mA
IDPM	VDPM Charge Current			20		µA
t_{DEL}	DELAY Time	CE = 470pF, RE = 33kΩ		1.9		µs

Electrical Specifications V_{IN} = ENABLE = 5V, V_{DD1} = V_{DD2} = 14V, V_{GH} = 25V, AV_{DD} = 10V, T_A = -40°C to +85°C
Unless Otherwise Noted. **Boldface limits apply over the operating temperature range, -40°C to +85°C. (Continued)**

SYMBOL	PARAMETER	TEST CONDITION	MIN (Note 6)	TYP	MAX (Note 6)	UNIT
SUPPLY MONITOR						
V_{IH_VDIV}	VDIV High Threshold	VDIV rising	**1.18**			V
V_{IL_VDIV}	VDIV Low Threshold	VDIV falling			**1.05**	V
I_{CD2}	CD2 Charge Current			10		μA
R_{IL_RESET}	RESET Pull-Down Resistance			750		Ω
t_{DELAY_RESET}	RESET Delay on the Rising Edge			121.5k*CD		s

NOTE:

6. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.

Typical Performance Curves
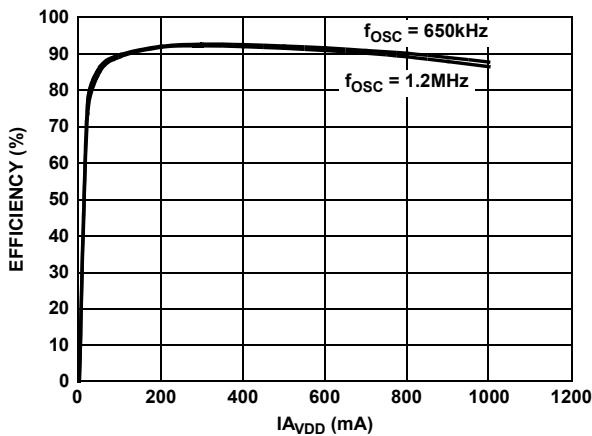
FIGURE 1. A_{VDD} EFFICIENCY vs IA_{VDD}
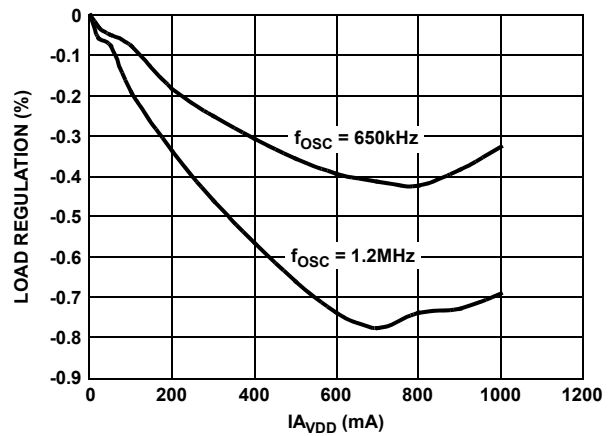
FIGURE 2. A_{VDD} LOAD REGULATION vs IA_{VDD}
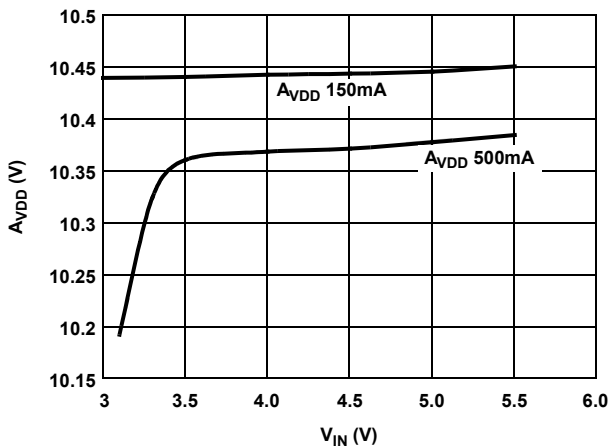
FIGURE 3. LINE REGULATION A_{VDD} vs V_{IN}
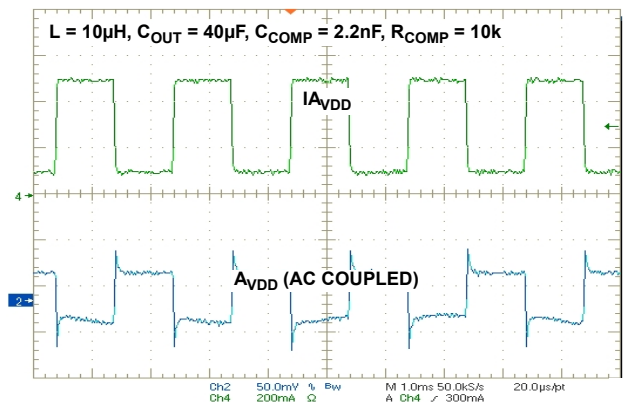
FIGURE 4. BOOST CONVERTER TRANSIENT RESPONSE

Typical Performance Curves (Continued)
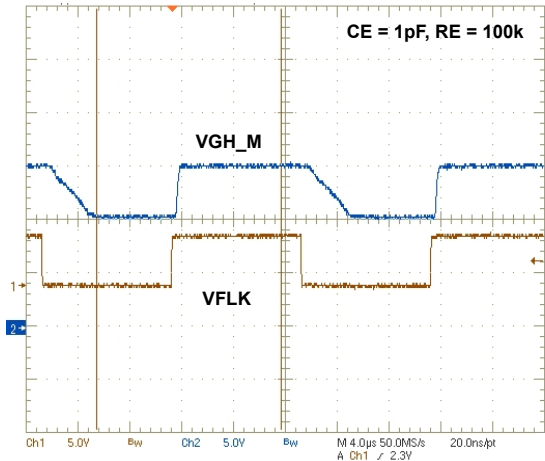
FIGURE 5. GPM CIRCUIT WAVEFORM
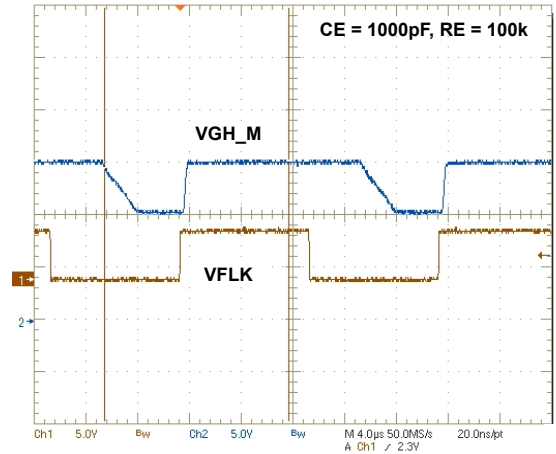
FIGURE 6. GPM CIRCUIT WAVEFORM
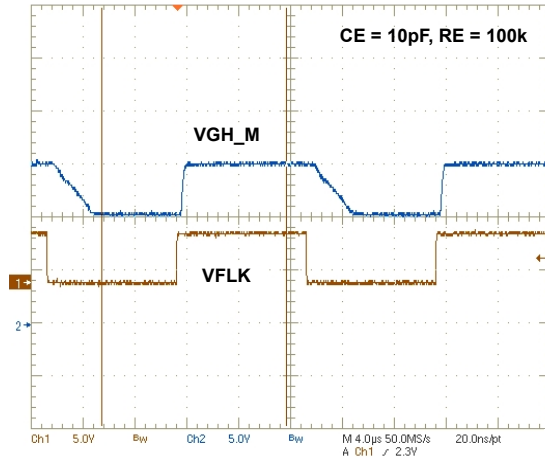
FIGURE 7. GPM CIRCUIT WAVEFORM
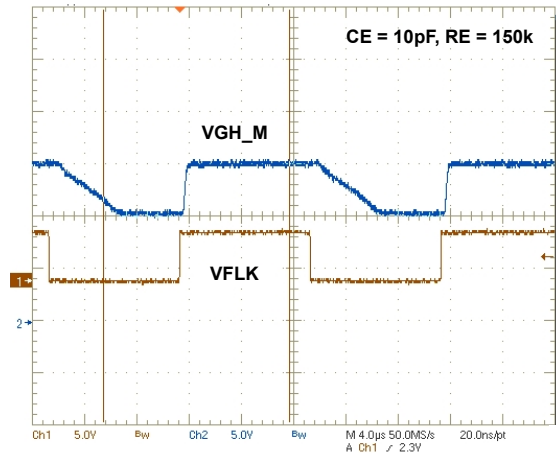
FIGURE 8. GPM CIRCUIT WAVEFORM
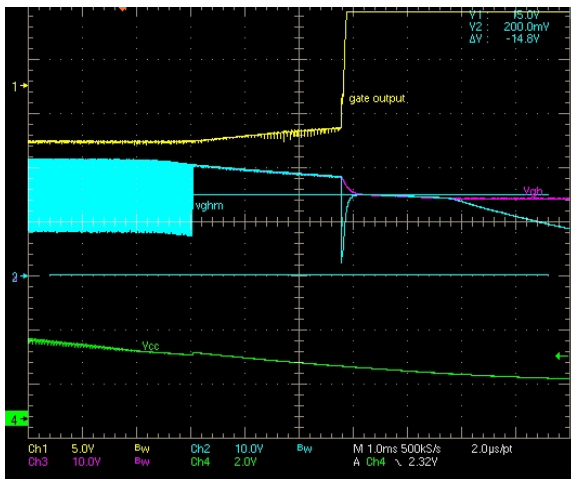
FIGURE 9. V_{GHM} FOLLOWS V_{GH} WHEN THE SYSTEM POWERS OFF
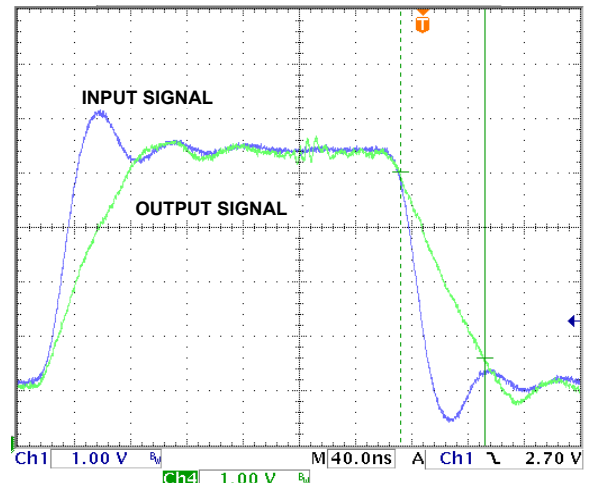

FIGURE 10. V_{COM} RISING SLEW RATE

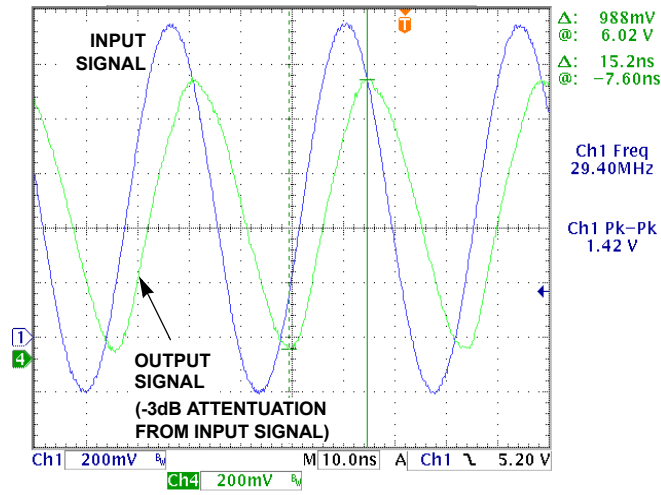## *Typical Performance Curves* (Continued)
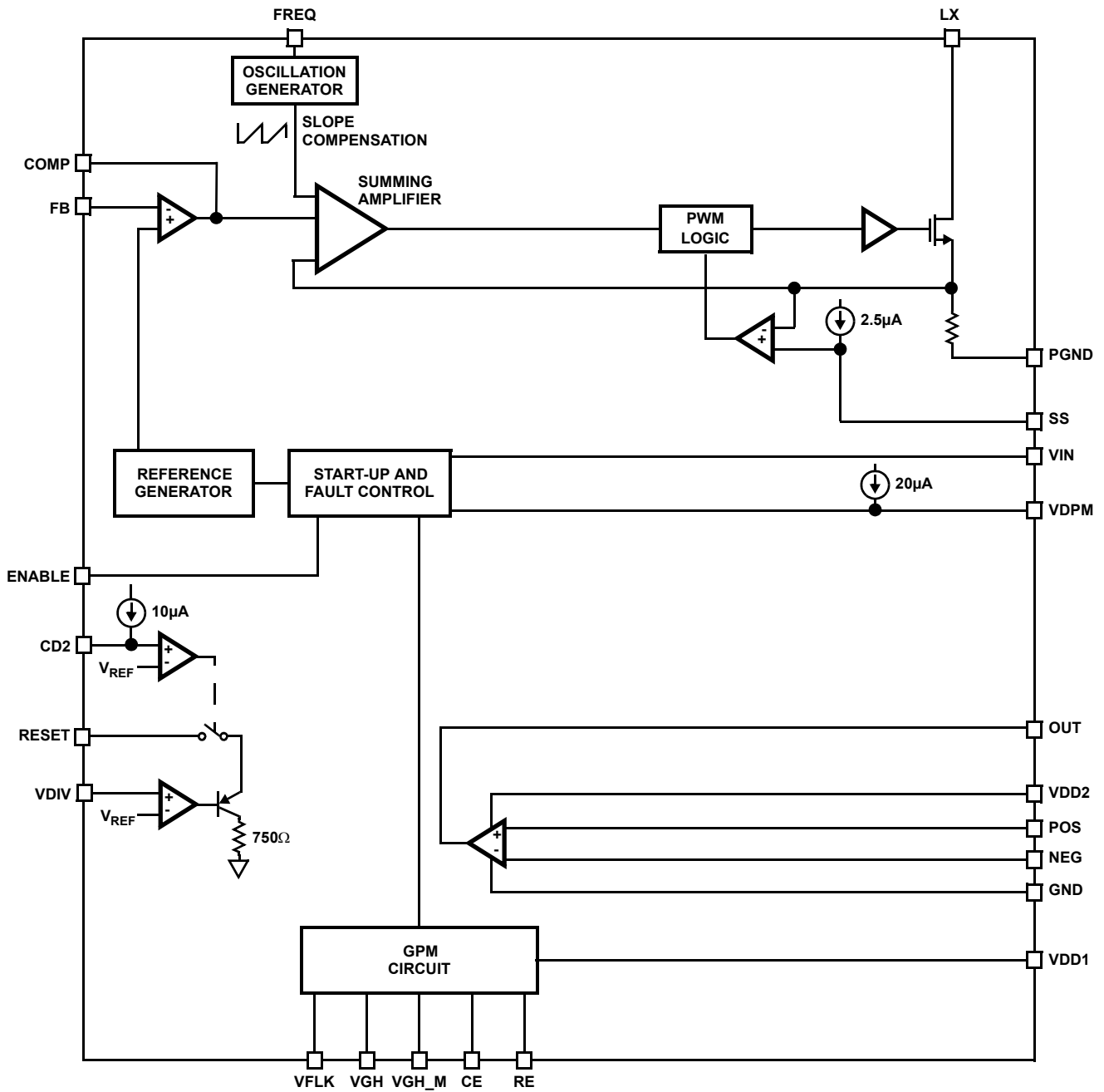

FIGURE 11. V$_{COM}$ BANDWIDTH MEASUREMENT

Block Diagram
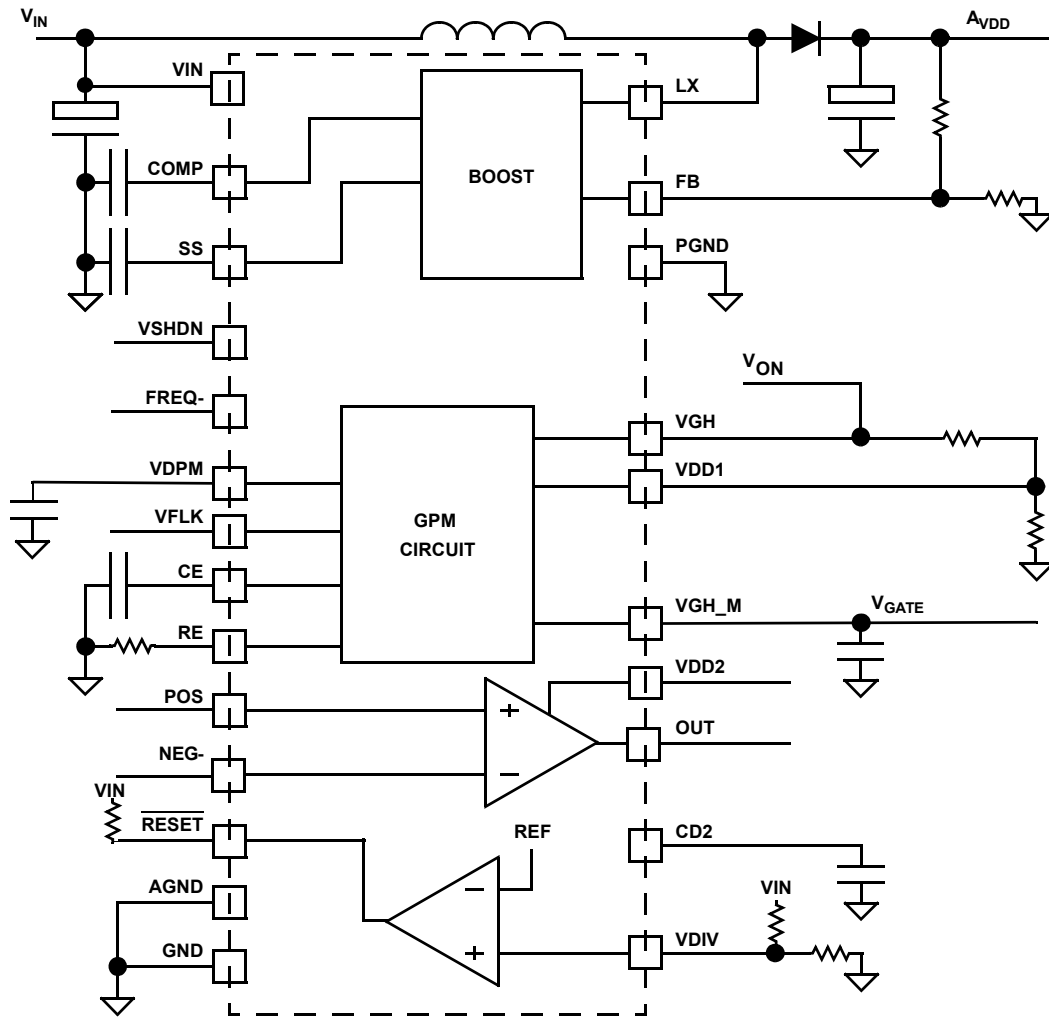

FIGURE 12. ISL97645A BLOCK DIAGRAM

Functional Block Diagram

FIGURE 13. FUNCTIONAL BLOCK DIAGRAM

Applications Information

The ISL97645A provides a complete power solution for TFT LCD applications. The system consists of one boost converter to generate A_{VDD} voltage for column drivers, one integrated V_{COM} buffer which can provide up to 400mA peak current, and one supply monitor to generate the reset signal when the input voltage is low. This part also integrates Gate Pulse Modulator circuit that can help to optimize the picture quality.

Enable Control

When enable pin is pulling down, the ISL97645A is shut down reducing the supply current to <10µA. When the voltage at enable pin reaches 2.2V, the ISL97645A is on.

Boost Converter

Frequency Selection

The ISL97645A switching frequency can be user selected to operate at either constant 650kHz or 1.2MHz. Lower switching frequency can save power dissipation, while higher switching frequency can allow smaller external components like inductor and output capacitors, etc. Connecting the FREQ pin to GND sets the PWM switching frequency to 650kHz, or connecting FREQ pin to V_{IN} for 1.2MHz.

Soft-Start

The soft-start is provided by an internal 2.5µA current source to charge the external soft-start capacitor. The ISL97645A ramps up current limit from 0A up to full value, as the voltage at SS pin ramps from 0 to 1.2V. Hence the soft-start time is 4.8ms when the soft-start capacitor is 10nF, 22.6ms for 47nF and 48ms for 100nF.

Operation

The boost converter is a current mode PWM converter operating at either a 650kHz or 1.2MHz. It can operate in both discontinuous conduction mode (DCM) at light load and continuous mode (CCM). In continuous current mode, current flows continuously in the inductor during the entire switching cycle in steady state operation. The voltage conversion ratio in continuous current mode is given by Equation 1:

$$\frac{V_{Boost}}{V_{IN}} = \frac{1}{1-D} \qquad \text{(EQ. 1)}$$

Where D is the duty cycle of the switching MOSFET.

Figure 12 shows the block diagram of the boost regulator. It uses a summing amplifier architecture consisting of gm stages for voltage feedback, current feedback and slope compensation. A comparator looks at the peak inductor current cycle by cycle and terminates the PWM cycle if the current limit is reached.

An external resistor divider is required to divide the output voltage down to the nominal reference voltage. Current drawn by the resistor network should be limited to maintain the overall converter efficiency. The maximum value of the resistor network is limited by the feedback input bias current and the potential for noise being coupled into the feedback pin. A resistor network in the order of 60kΩ is recommended. The boost converter output voltage is determined by Equation 2:

$$V_{Boost} = \frac{R_1 + R_2}{R_2} \times V_{FB} \qquad \text{(EQ. 2)}$$

The current through the MOSFET is limited to 2.6A$_{PEAK}$.

This restricts the maximum output current (average) based on Equation 3:

$$I_{OMAX} = \left(I_{LMT} - \frac{\Delta I_L}{2} \right) \times \frac{V_{IN}}{V_O} \qquad \text{(EQ. 3)}$$

Where ΔI_L is peak to peak inductor ripple current, and is set by Equation 4:

$$\Delta I_L = \frac{V_{IN}}{L} \times \frac{D}{f_s} \qquad \text{(EQ. 4)}$$

where f_S is the switching frequency (650kHz or 1.2MHz).

Table 2 gives typical values (margins are considered 10%, 3%, 20%, 10% and 15% on V_{IN}, V_O, L, f_S and I_{OMAX}).

Capacitor

An input capacitor is used to suppress the voltage ripple injected into the boost converter. The ceramic capacitor with capacitance larger than 10µF is recommended. The voltage rating of input capacitor should be larger than the maximum input voltage. Some capacitors are recommended in Table 1 for input capacitor.

TABLE 1. BOOST CONVERTER INPUT CAPACITOR RECOMMENDATION

CAPACITOR	SIZE	MFG	PART NUMBER
10µF/16V	1206	TDK	C3216X7R1C106M
10µF/10V	0805	Murata	GRM21BR61A106K
22µF/10V	1210	Murata	GRB32ER61A226K

TABLE 2. MAXIMUM OUTPUT CURRENT CALCULATION

V_{IN} (V)	V_O (V)	L (µH)	F_S (MHz)	I_{OMAX} (mA)
3	9	10	0.65	636
3	12	10	0.65	419
3	15	10	0.65	289
5	9	10	0.65	1060
5	12	10	0.65	699
5	15	10	0.65	482
5	18	10	0.65	338
3	9	10	1.2	742
3	12	10	1.2	525
3	15	10	1.2	395
5	9	10	1.2	1236
5	12	10	1.2	875
5	15	10	1.2	658
5	18	10	1.2	514

RENESAS

Inductor

The boost inductor is a critical part which influences the output voltage ripple, transient response, and efficiency. Values of 3.3µH to 10µH are used to match the internal slope compensation. The inductor must be able to handle the following average and peak current are in Equation 5:

$$I_{LAVG} = \frac{I_O}{1-D}$$

$$I_{LPK} = I_{LAVG} + \frac{\Delta I_L}{2}$$

(EQ. 5)

Some inductors are recommended in Table 3.

TABLE 3. BOOST INDUCTOR RECOMMENDATION

INDUCTOR	DIMENSIONS (mm)	MFG	PART NUMBER
6.8µH/3A$_{PEAK}$	7.3x6.8x3.2	TDK	RLF7030T-6R8N3R0
10µH/4A$_{PEAK}$	8.3x8.3x4.5	Sumida	CDR8D43-100NC
5.2µH/4.55A$_{PEAK}$	10x10.1x3.8	Cooper Bussmann	CD1-5R2

Rectifier Diode

A high-speed diode is necessary due to the high switching frequency. Schottky diodes are recommended because of their fast recovery time and low forward voltage. The reverse voltage rating of this diode should be higher than the maximum output voltage. The rectifier diode must meet the output current and peak inductor current requirements. The following table is some recommendations for boost converter diode.

TABLE 4. BOOST CONVERTER RECTIFIER DIODE RECOMMENDATION

DIODE	V_R/I_{AVG} RATING	PACKAGE	MFG
SS23	30V/2A	SMB	Fairchild Semiconductor
MBRS340	40V/3A	SMC	International Rectifier
SL23	30V/2A	SMB	Vishay Semiconductor

Output Capacitor

The output capacitor supplies the load directly and reduces the ripple voltage at the output. Output ripple voltage consists of two components:

1. the voltage drop due to the inductor ripple current flowing through the ESR of output capacitor.
2. charging and discharging of the output capacitor.

$$V_{RIPPLE} = I_{LPK} \times ESR + \frac{V_O - V_{IN}}{V_O} \times \frac{I_O}{C_{OUT}} \times \frac{1}{f_s}$$

(EQ. 6)

For low ESR ceramic capacitors, the output ripple is dominated by the charging and discharging of the output capacitor. The voltage rating of the output capacitor should be greater than the maximum output voltage.

Note: Capacitors have a voltage coefficient that makes their effective capacitance drop as the voltage across then increases. C_{OUT} in the equation above assumes the effective value of the capacitor at a particular voltage and not the manufacturer's stated value, measured at 0V.

Table 5 shows some selections of output capacitors.

TABLE 5. BOOST OUTPUT CAPACITOR RECOMMENDATION

CAPACITOR	SIZE	MFG	PART NUMBER
10µF/25V	1210	TDK	C3225X7R1E106M
10µF/25V	1210	Murata	GRM32DR61E106K

Compensation

The boost converter of ISL97645A can be compensated by a RC network connected from CM1 pin to ground. 4.7nF and 10k RC network is used in the demo board. The larger value resistor and lower value capacitor can lower the transient overshoot, however, at the expense of stability of the loop.

Cascaded MOSFET Application

An 20V N-Channel MOSFET is integrated in the boost regulator. For the applications where the output voltage is greater than 20V, an external cascaded MOSFET is needed as shown in Figure 14. The voltage rating of the external MOSFET should be greater than A_{VDD}.
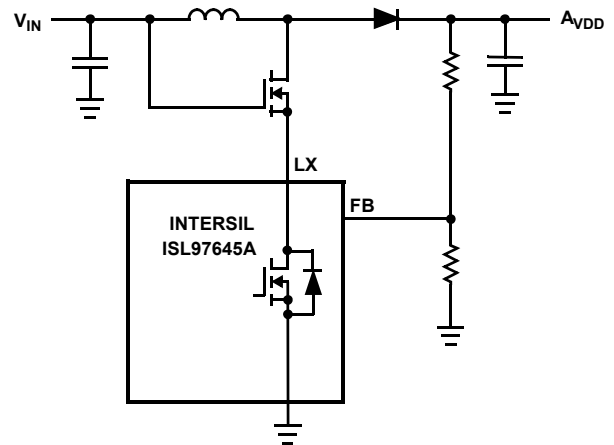

FIGURE 14. CASCADED MOSFET TOPOLOGY FOR HIGH OUTPUT VOLTAGE APPLICATIONS

Supply Monitor Circuit

The Supply Monitor circuit monitors the voltage on VDIV, and sets open-drain output RESET low when VDIV is below 1.15V (rising) or 1.1V (falling).

There is a delay on the rising edge, controlled by a capacitor on CD2. When VDIV exceeds 1.15V (rising), CD2 is charged up from 0V to 1.215V by a 10µA current source. Once CD2 exceeds 1.215V, RESET will go tri-state. When VDIV falls below 1.1V, RESET will become low with a 750 pull-down resistance. The delay time is controlled by Equation 7:

$$t_{delay} = 121.5k \times CD2 \qquad \text{(EQ. 7)}$$

For example, the delay time is 12.15ms if the CD2 = 100nF.

Figure 15 is the Supply Monitor Circuit timing diagram.
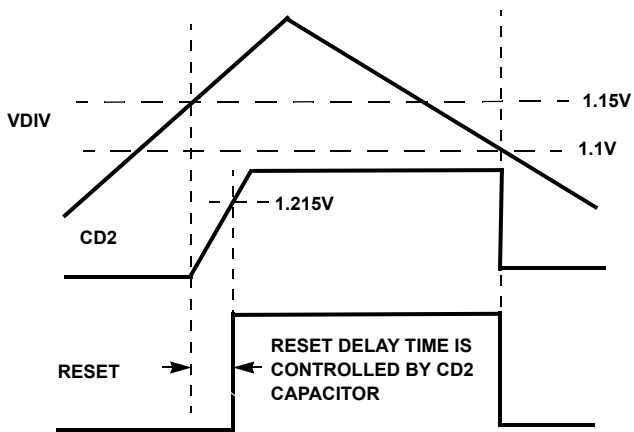
FIGURE 15. SUPPLY MONITOR CIRCUIT TIMING DIAGRAM

Gate Pulse Modulator Circuit

The gate pulse modulator circuit functions as a three way multiplexer, switching VGHM between ground, VDD1 and VGH. Voltage selection is provided by digital inputs VDPM (enable) and VFLK (control). High to low delay and slew control is provided by external components on pins CE and RE, respectively. A block diagram of the gate pulse modulator circuit is shown in Figure 16.

When VDPM is LOW, the block is disabled and VGHM is grounded. When the input voltage exceeds UVLO threshold, VDPM starts to drive an external capacitor with 20µA. Once VDPM exceeds 1.215V, the GPM circuit is enabled, and the output VGH_M is determined by VFLK, RESET signal and VGH voltage. If RESET signal is high, and when VFLK goes high, VGHM is pulled to VGH by a 70Ω switch. When VFLK goes low, there is a delay controlled by capacitor CE, following which VGHM is driven to VDD1, with a slew rate controlled by resistor RE. Note that VDD1 is used only as a reference voltage for an amplifier, thus does not have to source or sink a significant DC current.

Low to high transition is determined primarily by the switch resistance and the external capacitive load. High to low transition is more complex. Take the case where the block is already enabled (VDPM is H). When VFLK is H, pin CE is grounded. On the falling edge of VFLK, a current is passed into pin CE, to charge an external capacitor to 1.2V. This creates a delay, equal to CE*4200. At this point, the output begins to pull down from VGH to VDD1. The slew current is equal to 300/(RE + 5000), and the dv/dt slew rate is Isl/C_{LOAD}.

where C_{LOAD} is the load capacitance applied to VGHM.

When RESET signal changes to low, and VGH voltage is above 2.5V, the VGH_M will be tied to VGH voltage until the VGH voltage falls down to 2.5V. If the VGH voltage is lower than 2.5V, GPM block will not work properly, and there is no active control for VGH_M output. The following table shows the VGH_M status based on V_{IN}, VGH and RESET:
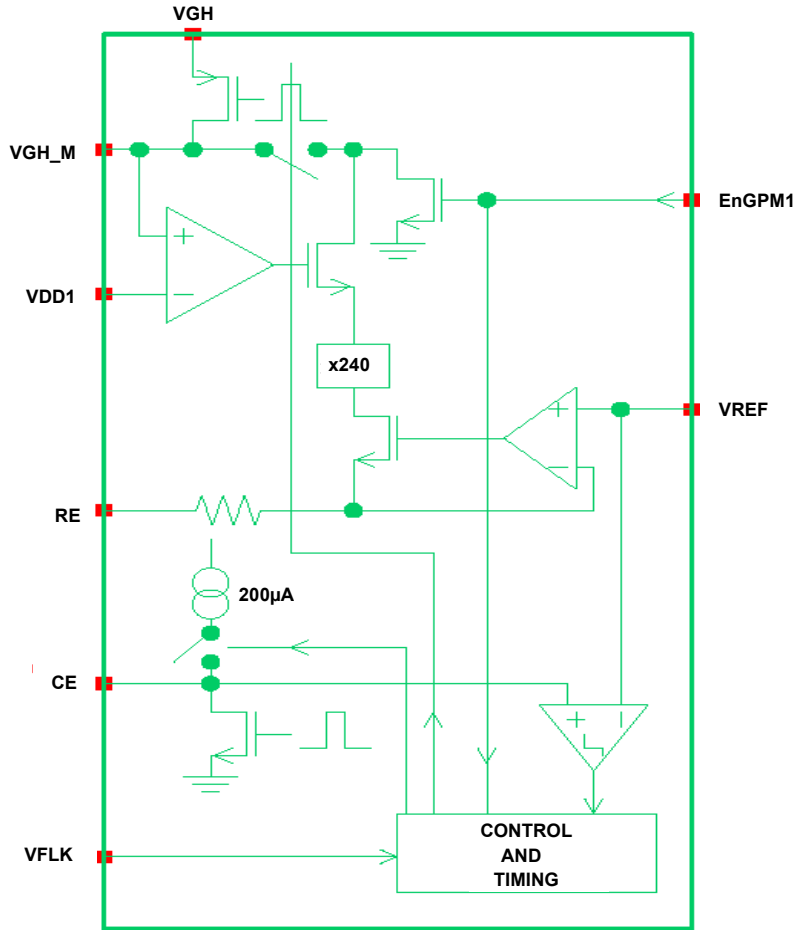
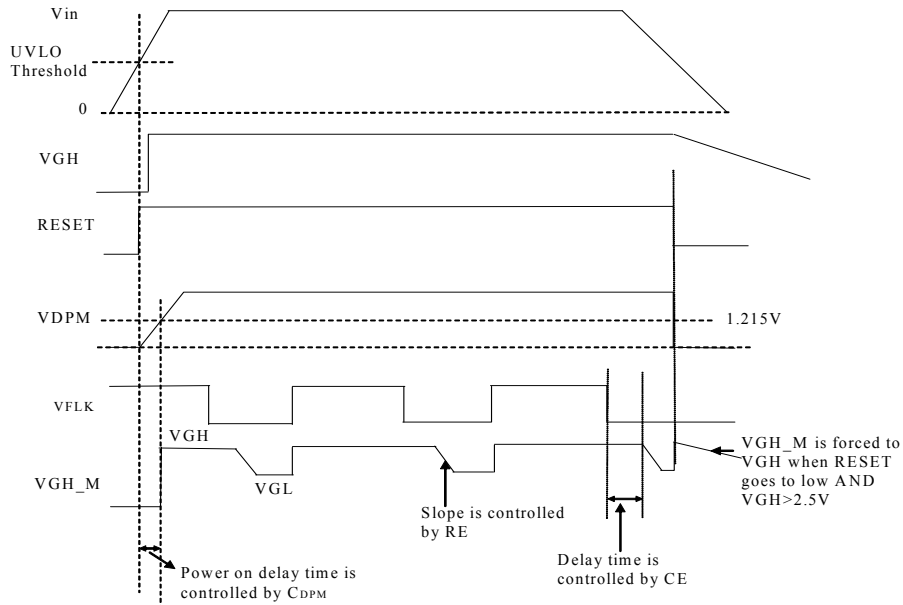**FIGURE 16. GATE PULSE MODULATOR CIRCUIT BLOCK DIAGRAM**

FIGURE 17. GATE PULSE MODULATOR TIMING DIAGRAM

TABLE 6. VGH_M STATUS TABLE

V$_{IN}$	VDPM	RESET	VGH	VGH_M	COMMENT
x	x	x	<2.5V	GROUND	Will be grounded if VIN is above a logic threshold. Could occur at power-up or power-down
>VLOR	<1.215V	x	>2.5V	GROUND	Start-up only condition: If either V$_{IN}$> VLOR or reset is H, but VDPM < 1.215V, GND VGHM
x	<1.215V	High	>2.5V	GROUND	
>VLOR	>1.215V	High	>2.5V	Switching controlled by VFLK	
x	x	Low	>2.5V	VGH	Power-down state. Could occur at power-up if part starts with VGH > 2.5V

Start-Up Sequence

When V$_{IN}$ exceeds VLOR and ENABLE reaches the VIH threshold value, Boost converter starts up, and gate pulse modulator circuit output holds until VDPM is charged to 1.215V. Note that there is a DC path in the boost converter from the input to the output through the inductor and diode, hence the input voltage will be seen at output with a forward voltage drop of diode before the part is enabled. If this voltage is not desired, the following circuit can be inserted between input and inductor to disconnect the DC path when the part is disabled.
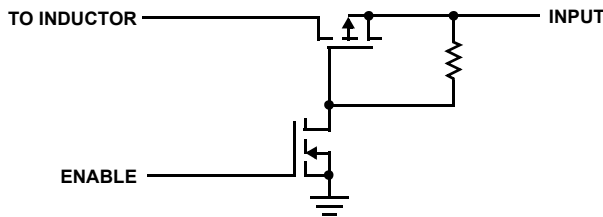
FIGURE 18. CIRCUIT TO DISCONNECT THE DC PATH OF BOOST CONVERTER

V$_{COM}$ Amplifier

The V$_{COM}$ amplifier is designed to control the voltage on the back plate of an LCD display. This plate is capacitively coupled to the pixel drive voltage which alternately cycles positive and negative at the line rate for the display. Thus the amplifier must be capable of sourcing and sinking capacitive pulses of current, which can occasionally be quite large (a few 100mA for typical applications).

The ISL97645A V$_{COM}$ amplifier's output current is limited to 400mA. This limit level, which is roughly the same for sourcing and sinking, is included to maintain reliable operation of the part. It does not necessarily prevent a large temperature rise if the current is maintained. (In this case the whole chip may be shut down by the thermal trip to protect functionality.) If the display occasionally demands current pulses higher than this limit, the reservoir capacitor will provide the excess and the amplifier will top the reservoir capacitor back up once the pulse has stopped. This will happen on the µs time scale in practical systems and for pulses 2 or 3 times the current limit, the V$_{COM}$ voltage will have settled again before the next line is processed.

Fault Protection

ISL97645A provides the overall fault protections including over current protection and over-temperature protection.

An internal temperature sensor continuously monitors the die temperature. In the event that die temperature exceeds the thermal trip point, the device will shut down and disable itself. The upper and lower trip points are typically set to +140°C and +100°C respectively.

Layout Recommendation

The device's performance including efficiency, output noise, transient response and control loop stability is dramatically affected by the PCB layout. PCB layout is critical, especially at high switching frequency.

There are some general guidelines for layout:

1. Place the external power components (the input capacitors, output capacitors, boost inductor and output diodes, etc.) in close proximity to the device. Traces to these components should be kept as short and wide as possible to minimize parasitic inductance and resistance.

2. Place V_{IN} and VDD bypass capacitors close to the pins.

3. Reduce the loop area with large AC amplitudes and fast slew rate.

4. The feedback network should sense the output voltage directly from the point of load, and be as far away from LX node as possible.

5. The power ground (PGND) and signal ground (SGND) pins should be connected at only one point.

6. The exposed die plate, on the underneath of the package, should be soldered to an equivalent area of metal on the PCB. This contact area should have multiple via connections to the back of the PCB as well as connections to intermediate PCB layers, if available, to maximize thermal dissipation away from the IC.

7. To minimize the thermal resistance of the package when soldered to a multi-layer PCB, the amount of copper track and ground plane area connected to the exposed die plate should be maximized and spread out as far as possible from the IC. The bottom and top PCB areas especially should be maximized to allow thermal dissipation to the surrounding air.

8. A signal ground plane, separate from the power ground plane and connected to the power ground pins only at the exposed die plate, should be used for ground return connections for control circuit.

9. Minimize feedback input track lengths to avoid switching noise pick-up.

A demo board is available to illustrate the proper layout implementation.

Package Outline Drawing

L24.4x4D
24 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE
Rev 2, 10/06

PIN 1
INDEX AREA

4.00

A
B

4.00

(4X) 0.15

TOP VIEW

4X 2.5
20X 0.50

PIN #1 CORNER
(C 0.25)

19   24

18   1

□ 2.50 ± 0.15

13

12   7

24X 0.4 ± 0.1

⊕ 0.10 Ⓜ C A B

24X 0.23 +0.07 −0.05 ◢4◣

BOTTOM VIEW

(3.8 TYP)

(□ 2.50)

(20X 0.5)

(24X 0.25)

(24X 0.6)

TYPICAL RECOMMENDED LAND PATTERN

SEE DETAIL "X"

0.90 ± 0.1

// 0.10 C

C

BASE PLANE

SIDE VIEW

SEATING PLANE

0.08 C

C   0.2 REF   ◢5◣

0.00 MIN.
0.05 MAX.

DETAIL "X"
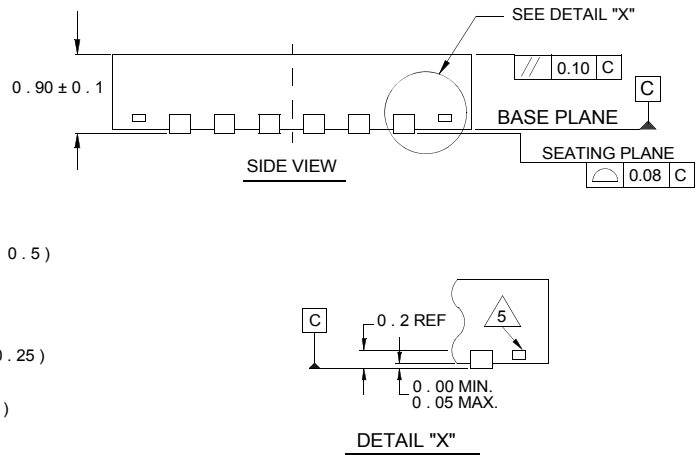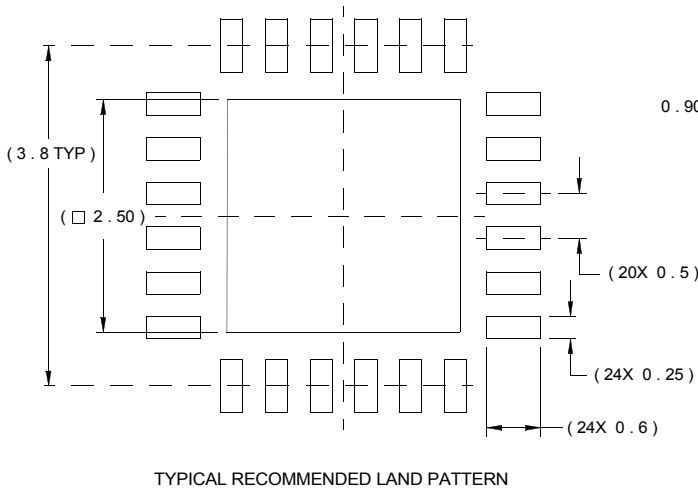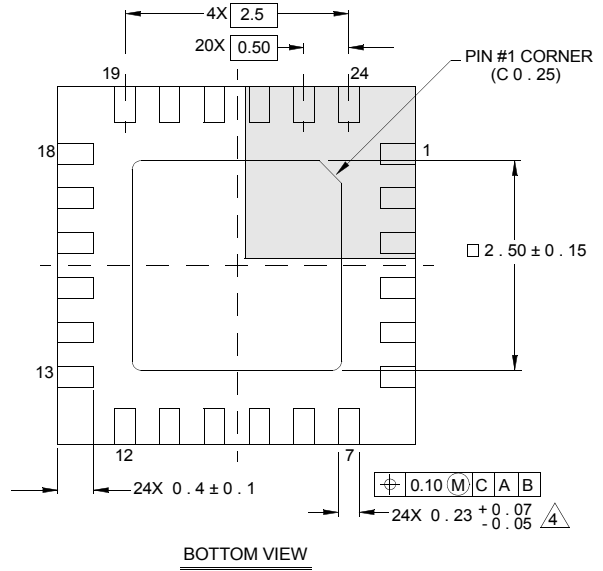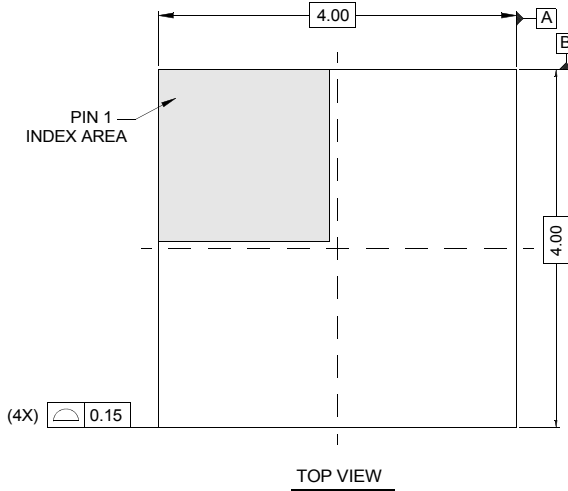
NOTES:

1. Dimensions are in millimeters.
   Dimensions in ( ) for Reference Only.

2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.

3. Unless otherwise specified, tolerance : Decimal ± 0.05

4. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.

5. Tiebar shown (if present) is a non-functional feature.

6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.

RENESAS